

Search History 10/13/04 (5 pp.)

L Number	Hits	Search Text	DB	Time stamp
1	4607	((257/48) or (438/18) or (324/158.1) or (324/133) or (324/501)).CCLS.	USPAT; US-PGPUB	2004/10/13 17:00
2	1	((257/48) or (438/18) or (324/158.1) or (324/133) or (324/501)).CCLS.) and (laser adj voltage adj probe lvp) near6 gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/10/13 17:01
3	317	((257/48) or (438/18) or (324/158.1) or (324/133) or (324/501)).CCLS.) and (test testing non-invasive laser adj voltage adj probe lvp) near6 gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/10/13 17:02
4	345	((257/48) or (438/18) or (324/158.1) or (324/133) or (324/501)).CCLS.) and (test testing non-invasive laser adj voltage adj probe lvp) near6 gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/10/13 17:02
-	0	(324/158).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/10/13 11:34
-	3960	324/158\$3.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/06/28 21:17
-	3960	324/158.\$3.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/06/28 21:17
-	0	lvp.ti,ab. and 257/\$6.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/06/28 21:20
-	2	lvp.ti,ab. and probe	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/06/28 21:20
-	24	lvp.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/06/28 21:21
-	4741	((257/48).CCLS.) or 324/158.\$3.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/06/29 12:55
-	7	((257/48).CCLS.) or 324/158.\$3.ccls.) and (mosfet or cmosfet or nmosfet or pmosfet or cmos or nmos or pmos) and (test or testing or diagnostic) near12 laser	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/08/05 15:36
-	8	((257/48).CCLS.) or 324/158.\$3.ccls.) and (mosfet or cmosfet or nmosfet or pmosfet or cmos or nmos or pmos) and (test or testing or diagnostic) near12 (optic or optical)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/06/29 13:01
-	2	((257/48).CCLS.) or 324/158.\$3.ccls.) and (mosfet or cmosfet or nmosfet or pmosfet or cmos or nmos or pmos) and (test or testing or diagnostic) near12 (pn adj junction)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/06/29 13:08

-	26	((257/48).CCLS.) or 324/158.\$3.ccls.) and (mosfet or cmosfet or nmosfet or pmosfet or cmos or nmos or pmos) and (test or testing or diagnostic) and (pn adj junction or p-n adj junction or pn-junction)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/29 13:15
-	3	laser near12 diagnostic near12 (np adj junction or n-p junction or np-junction)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/29 13:17
-	16	laser near12 (test or testing) near12 (np adj junction or n-p junction or np-junction)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/29 17:33
-	11	tsang.in. and kash.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/29 17:40
-	327	(324/501).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/29 17:41
-	801	(257/48).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/29 18:10
-	3960	324/158.\$4.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/29 18:15
-	8	324/158.\$4.ccls. and (pn adj junction or p-n adj junction or pn-junction or p-n-junction) and (laser or optical)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/05 19:09
-	280	(438/18).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/29 18:17
-	913	(257/48).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 16:34
-	91	((257/48).CCLS.) and test\$3 near6 gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 16:36
-	22	((257/48).CCLS.) and test\$3 near6 gate and (cmos or cmosfet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 16:38
-	3	((257/48).CCLS.) and test\$3 near6 gate and (cmos or cmosfet) and (laser or irradiat\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 17:15
-	0	((257/48).CCLS.) and optical near3 prob\$3 near6 gate and (cmos or cmosfet) and (laser or irradiat\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 17:16

	0	((257/48).CCLS.) and optical near3 prob\$3 near6 gate and (cmos or cmosfet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 17:17
	0	((257/48).CCLS.) and (laser or radiat\$3 or irradiat\$3) near6 prob\$3 near6 gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 17:18
	33	((257/48).CCLS.) and prob\$3 near6 gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 17:19
	31	(((257/48).CCLS.) and prob\$3 near6 gate) not (((257/48).CCLS.) and test\$3 near6 gate and (cmos or cmosfet))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 17:20
	24	((257/48).CCLS.) and laser near6 (test\$3 or prob\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 17:21
	38	((257/48).CCLS.) and (optical or laser) near6 (test\$3 or prob\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 17:26
	1	((257/48).CCLS.) and (lvp or laser adj voltage adj probe)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 17:27
	33	(lvp or laser adj voltage adj probe) and (mos or cmos or mosfet or cmosfet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 17:28
	3	(lvp or laser adj voltage adj probe) and (mos or cmos or mosfet or cmosfet) and (test\$3 or prob\$3) near6 gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 17:29
	44	(lvp or laser adj voltage adj probing).ti,ab,clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/03 20:39
	0	(back-side or backside or back adj side) near3 (lvp or laser adj voltage adj (probing or probe))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/04 09:54
	1	(back-side or backside or back adj side) near12 (lvp or laser adj voltage adj (probing or probe))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/04 10:05
	1	"6428718".PN.	USPAT	2003/03/04 09:57
	1	"6403439".PN.	USPAT	2003/03/04 10:03
	10	(lvp or laser adj voltage adj (probing or probe)) and (cmos or cmosfet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/04 10:59
	1	"6331453".PN.	USPAT	2003/03/04 10:09

		1	non-invasive near3 optical near12 (cmos or cmosfet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/03/04 10:15
		13	reverse adj voltage near6 (cmos or cmosfet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/03/04 11:01
		1	reverse adj voltage near6 (cmos or cmosfet) and (laser adj voltage adj (probing or probe))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/03/04 11:02
		11	reverse adj voltage near6 (cmos or cmosfet) and (test\$3 or prob\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/03/04 11:06
		2	reverse adj voltage near6 (cmos or cmosfet) and (test\$3 or probe or probing)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/03/04 12:00
		2	("6084267").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/03/04 12:00
		11	((257/48).CCLS.) or 324/158.\$3.ccls.) and (mosfet or cmosfet or nmosfet or pmosfet or cmos or nmos or pmos) and (test or testing or diagnostic) near12 laser	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/08/05 10:57
	3018	1	("6197109").PN.	USPAT	2003/08/05 15:37
	3018	77	324/158\$3.ccls. 257/48.ccls. 438/18.ccls.	USPAT; US-PGPUB	2003/08/05 19:09
		100	(324/158\$3.ccls. 257/48.ccls. 438/18.ccls.) and (lvp laser adj voltage adj probe laser-voltage-probe laser adj voltage-probe (laser near12 (test\$3 diagnostic\$1)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/08/05 19:12
		100	yoshida.in. and eiji.in.	USPAT; US-PGPUB	2003/08/06 08:42
		1	yoshida.in. and eiji.in. and transistor.clm. and laser.clm.	USPAT; US-PGPUB	2003/08/06 08:43
		6	yoshida.in. and eiji.in. and semiconductor and gate and laser	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/10/19 15:14
		2	("6137295").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/10/19 15:15
		6	392925.ap.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/10/19 15:27
	5806	5806	((324/158.1) or (324/501) or (257/48)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/10/19 15:27
		10	((324/158.1) or (324/501) or (257/48)).CCLS.) and laser near20 junction	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/10/19 15:41

-	398	(438/18).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT	2003/10/19 15:41
-	2	((438/18).CCLS.) and laser near20 junction		2003/10/19 15:41
-	6	lvp.ti,ab,clm. and probe		2003/10/19 15:56
-	437	cmos.ti,ab,clm. and drain near3 (connect connected) near3 source and common near2 (source drain)		2003/10/19 18:18
-	109	cmos.ti,ab,clm. and drain near3 (connect connected) near3 source and common near2 (source drain) and 257/\$9.ccls.	USPAT	2003/10/19 18:19
-	299	nmos near12 pmos and common adj (source drain) and 257/\$9.ccls.	USPAT; EPO; JPO	2003/10/19 19:45
-	0	dillinger.in. and protection and gate	USPAT; EPO; JPO; DERWENT	2003/10/19 19:48
-	74	latchup and testing and (257/\$9.ccls. 438/\$9.ccls.)	USPAT; EPO; JPO; DERWENT	2003/10/19 19:53
-	9	(latchup latch-up) near12 testing and (257/\$9.ccls. 438/\$9.ccls.)	USPAT; EPO; JPO; DERWENT	2003/10/19 20:10
-	1012	(257/48).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/10/19 20:11
-	1012	(257/48).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT	2003/10/19 20:11
-	542	(257/48).CCLS.	USPAT	2003/10/19 20:13
-	27	((257/48).CCLS.) and pmos and nmos	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT	2003/10/19 20:13
-	3	931104.ap.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/10/13 17:00